

20 V, P-channel Trench MOSFET 24 January 2014

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1 kV HBM
- Drain-source on-state resistance R_{DSon} = 350 mΩ

3. Applications

- High-side load switch and charging switch for portable devices
- Power management in battery driven portables
- LED driver
- DC-to-DC converter

4. Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-	-1.2	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -1.2 A; T _j = 25 °C		-	350	447	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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20 V, P-channel Trench MOSFET

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	4 3	G (The second s
4	D	drain	Transparent top view DFN1010D-3 (SOT1215)	S 017aaa259

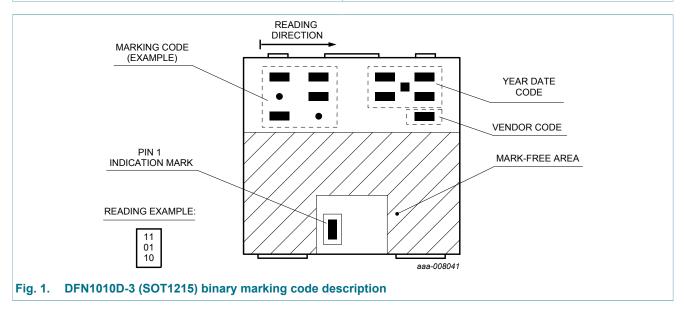
6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMXB350UPE	DFN1010D-3	DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm	SOT1215				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMXB350UPE	11 10 00



PMXB350UPE

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20 V, P-channel Trench MOSFET

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-1.2	А
		V_{GS} = -4.5 V; T_{amb} = 100 °C	[1]	-	-1	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-5	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	360	mW
			[1]	-	930	mW
		T _{sp} = 25 °C		-	5680	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	-0.9	А

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

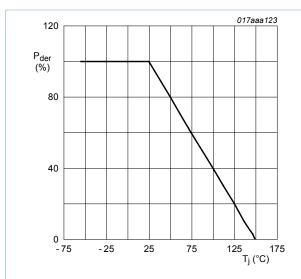
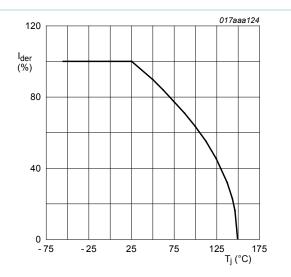


Fig. 2. Normalized total power dissipation as a function of junction temperature

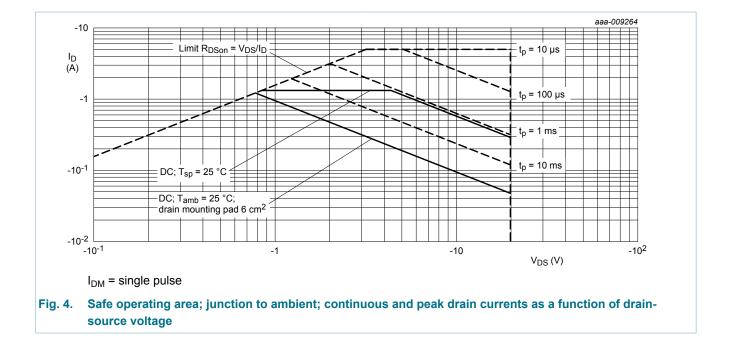
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$





$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

20 V, P-channel Trench MOSFET



9. Thermal characteristics

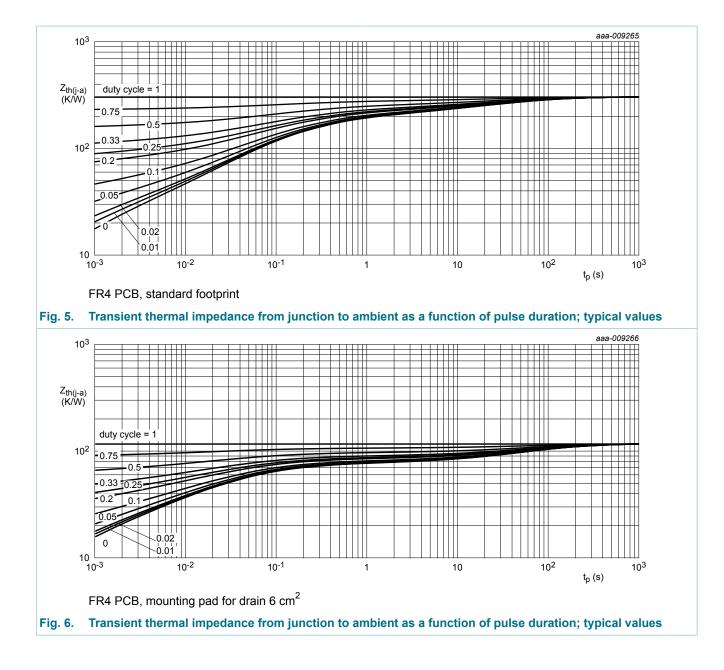
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistancein free airfrom junction toambient	in free air	[1]	-	303	348	K/W
			[2]	-	116	134	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	17	22	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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20 V, P-channel Trench MOSFET



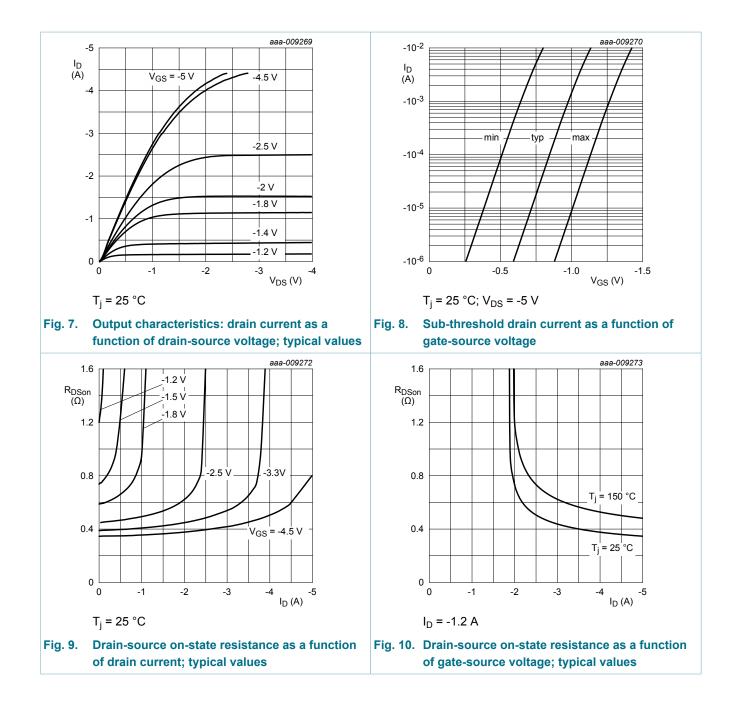
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · ·			_	
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
R _{DSon}	drain-source on-state	V _{GS} = -4.5 V; I _D = -1.2 A; T _j = 25 °C	-	350	447	mΩ
	resistance	V _{GS} = -4.5 V; I _D = -1.2 A; T _j = 150 °C	-	508	650	mΩ
		V _{GS} = -2.5 V; I _D = -1 A; T _j = 25 °C	-	450	645	mΩ
		V _{GS} = -1.8 V; I _D = -0.4 A; T _j = 25 °C	-	600	940	mΩ
		V _{GS} = -1.5 V; I _D = -10 mA; T _j = 25 °C	-	760	2000	mΩ
		V _{GS} = -1.2 V; I _D = -1 mA; T _j = 25 °C	-	1200	-	mΩ
9 _{fs}	forward transconductance	V _{DS} = -5 V; I _D = -1.2 A; T _j = 25 °C	-	5.2	-	S
R _G	gate resistance	f = 1 MHz	-	0.8	-	Ω
Dynamic ch	aracteristics		I			
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -1.2 A; V _{GS} = -4.5 V;	-	1.25	2.3	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.27	-	nC
Q _{GD}	gate-drain charge		-	0.28	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	116	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	16.5	-	pF
C _{rss}	reverse transfer capacitance		-	12.2	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -1.2 A; V _{GS} = -4.5 V;	-	3	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	9	-	ns
t _{d(off)}	turn-off delay time		-	18	-	ns
t _f	fall time		-	6	-	ns
Source-drai	in diode	· · · · · · · · · · · · · · · · · · ·				
V _{SD}	source-drain voltage	I _S = -0.9 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.8	-1.2	V

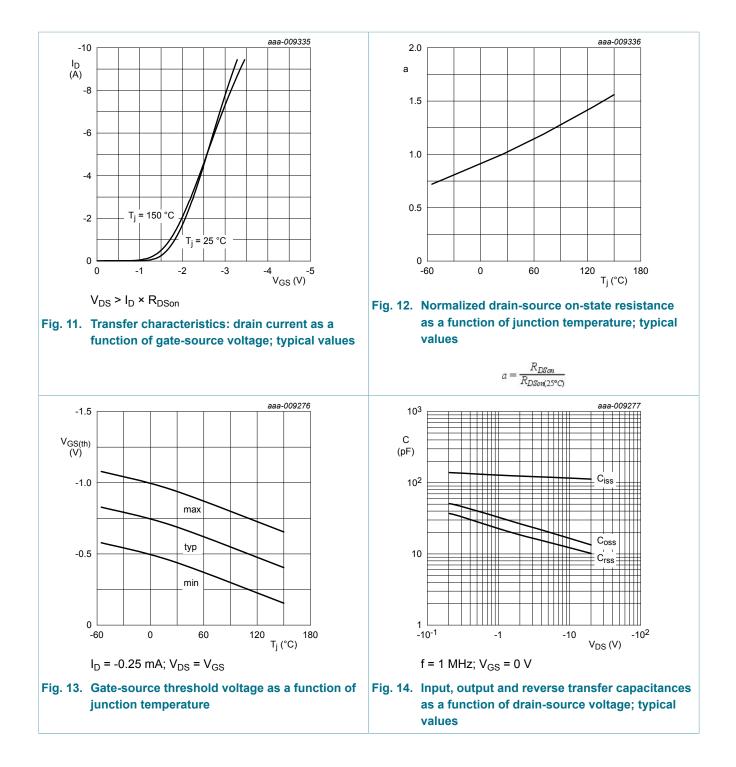
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20 V, P-channel Trench MOSFET



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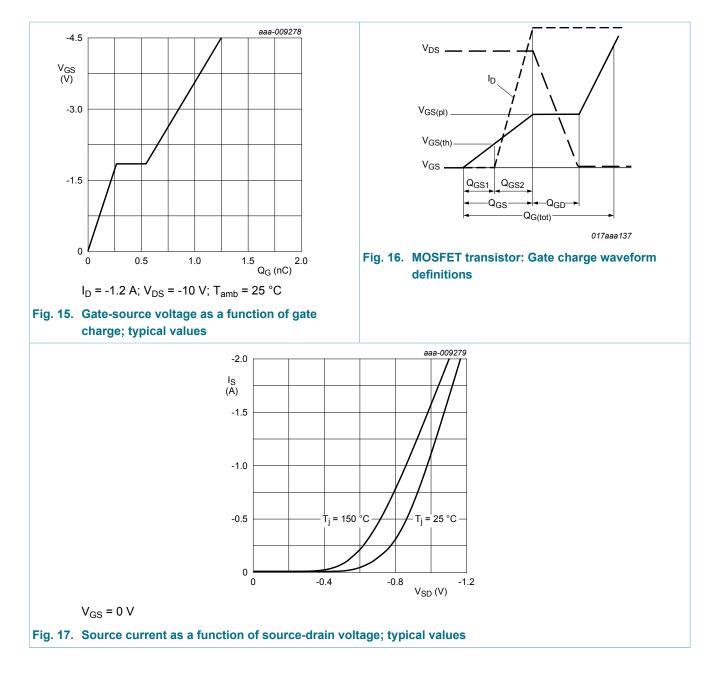
20 V, P-channel Trench MOSFET



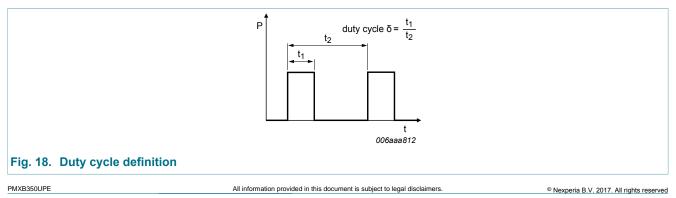
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20 V, P-channel Trench MOSFET

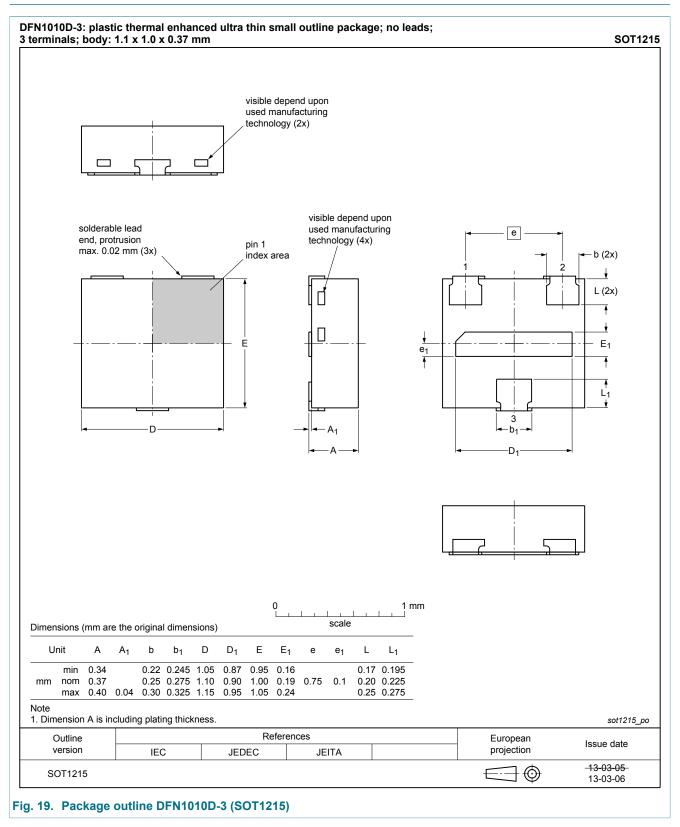


11. Test information



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12. Package outline



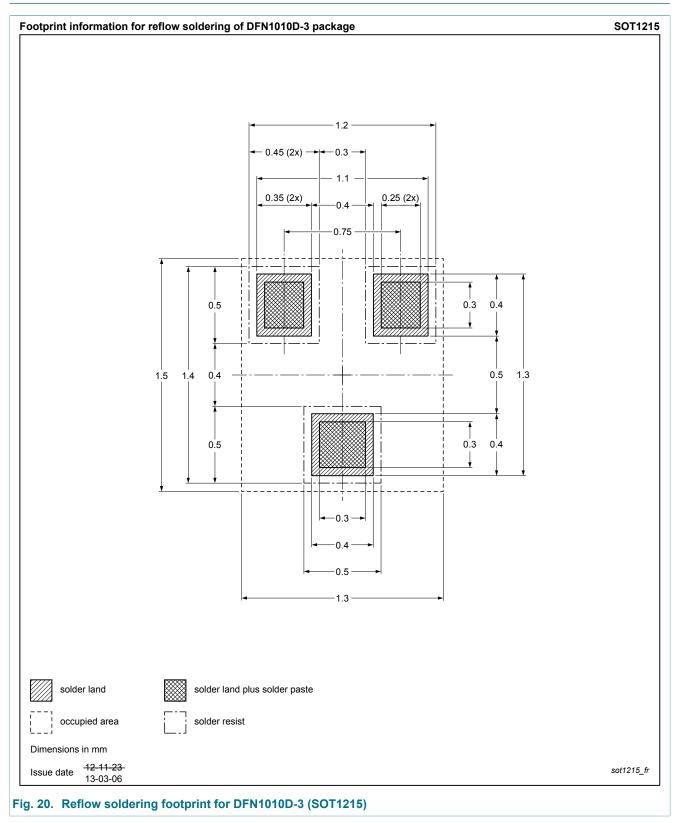
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20 V, P-channel Trench MOSFET

13. Soldering



20 V, P-channel Trench MOSFET

14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMXB350UPE v.2	20140124	Product data sheet	-	PMXB350UPE v.1
Modifications:	Editorial update			
PMXB350UPE v.1	20130919	Product data sheet	-	-

20 V, P-channel Trench MOSFET

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15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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20 V, P-channel Trench MOSFET

16. Contents

1	General description1
2	Features and benefits1
3	Applications1
4	Quick reference data1
5	Pinning information2
6	Ordering information2
7	Marking2
8	Limiting values3
9	Thermal characteristics4
10	Characteristics6
11	Test information9
12	Package outline 10
13	Soldering11
14	Revision history12
15	Legal information13
15.1	Data sheet status 13
15.2	Definitions13
15.3	Disclaimers13
15.4	Trademarks 14

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